NSN 5962-01-193-5810

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View Online at https://aerobasegroup.com/nsn/5962-01-193-5810

Body Length:
0.785 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.140 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+110.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
4920-01-148-5597 digital test st
Features Provided:
Hermetically sealed and monolithic and dynamic
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
12 input
Case Outline Source And Designator:
D-2 mil-m-38510
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Memory Capacity:
Unknown
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bu
format: excludes commercial catalogs industry directories a

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

16 printed circuit

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Specification Data:

81349-mil-m-38510/244 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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